Vishay Semiconductors

Schottky Rectifier, 10 A

Base cathode

Ó 1

Anode

Q 4, 2

D-PAK (TO-252AA)

10 A

45 V

0.57 V

15 mA at 125 °C

175 °C

Single die

20 mJ

ÓЗ

Anode



- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^\circ\text{C}$

DESCRIPTION

The VS-STPS1045BPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | | |
|-----------------------------------|---------------------------------|-------------|-------|--|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | | | |
| I _{F(AV)} | Rectangular waveform | 10 | A | | | | | | |
| V _{RRM} | | 45 | V | | | | | | |
| I _{FSM} | t _p = 5 μs sine | 390 | А | | | | | | |
| V _F | 10 Apk, T _J = 125 °C | 0.57 | V | | | | | | |
| TJ | Range | - 40 to 175 | °C | | | | | | |

| VOLTAGE RATINGS | | | | | | | | |
|--------------------------------------|------------------|-----------------|-------|--|--|--|--|--|
| PARAMETER | SYMBOL | VS-STPS1045BPbF | UNITS | | | | | |
| Maximum DC reverse voltage | V _R | 45 | V | | | | | |
| Maximum working peak reverse voltage | V _{RWM} | 45 | V | | | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|--|--------------------|---|---|-------|---|--|--|--|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | | | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T _C = 151 °C | 10 | | | | | | |
| Maximum peak one cycle non-repetitive surge current | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 390 | А | | | | |
| See fig. 7 | IFSM | 10 ms sine or 6 ms rect. pulse | 75 | | | | | | |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 \text{ °C}, I_{AS} = 3.0 \text{ A}, L = 4.40$ | 20 | mJ | | | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical | | 3.0 | А | | | | |

Document Number: 94323 Revision: 14-Jan-11 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

www.vishay.com





D-PAK (TO-252AA)

PRODUCT SUMMARY Package

> I_{F(AV)} V_R

V_F at I_F

 I_{RM}

T_{.1} max.

Diode variation

 E_{AS}

Vishay Semiconductors

Schottky Rectifier, 10 A



| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|---------------------------------|--------------------------------|--|---------------------------------|-------|----|--|--|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | | | |
| | | 10 A | T _{.1} = 25 °C | 0.63 | V | | | |
| Maximum forward voltage drop | V (1) | 20 A | $1_{\rm J} = 25$ C | 0.84 | | | | |
| See fig. 1 | V _{FM} ⁽¹⁾ | 10 A | T 105 %C | 0.57 | | | | |
| | | 20 A | T _J = 125 °C | 0.72 | | | | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | $V_{\rm B}$ = Rated $V_{\rm B}$ | 0.2 | mA | | | |
| See fig. 2 | IRM (") | T _J = 125 °C | VR = haleu VR | 15 | | | | |
| Typical junction capacitance | CT | V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 $^{\circ}\text{C}$ | | 760 | pF | | | |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 5.0 | nH | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | | | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|---|--|--|-------------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | |
| Maximum junction and storage temperature range | T _J ⁽¹⁾ , T _{Stg} | | - 40 to 175 | °C | | | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation See fig. 4 | 3.0 | °C/W | | | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | | 50 | C/W | | | | |
| Approvimento usiabt | | | 0.3 | g | | | | |
| Approximate weight | | | 0.01 | oz. | | | | |
| Marking device | | Case style D-PAK (similar to TO-252AA) | STPS | 1045B | | | | |

Note

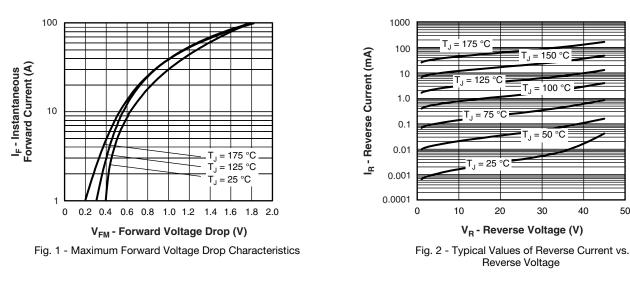
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 10 A

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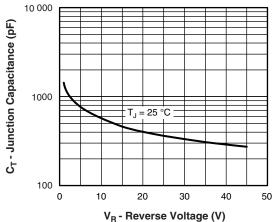


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

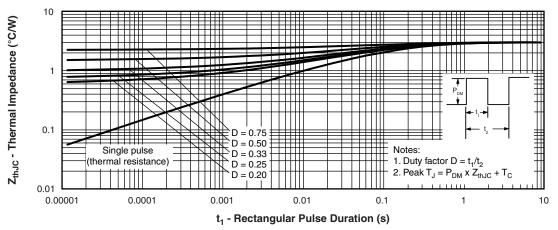


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

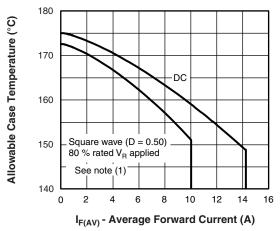
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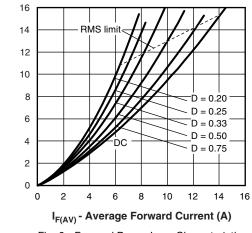
Schottky Rectifier, 10 A

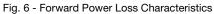
Average Power Loss (W)

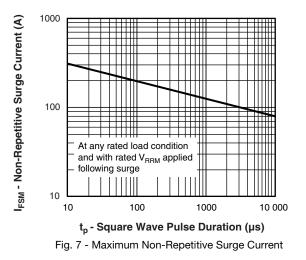












Note

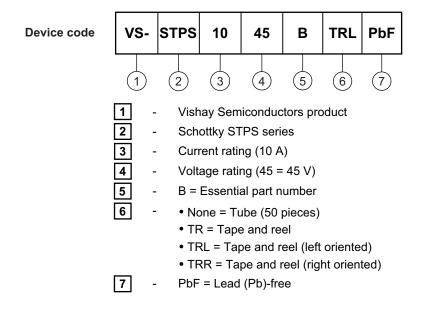
- (1)
- $\begin{array}{l} \mbox{Formula used: } T_C = T_J \mbox{ } (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{Forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \ Inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 \ D); \ I_R \ at \ V_{R1} = 80 \ \% \ rated \ V_R \end{array}$



Schottky Rectifier, 10 A

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ORDERING INFORMATION TABLE



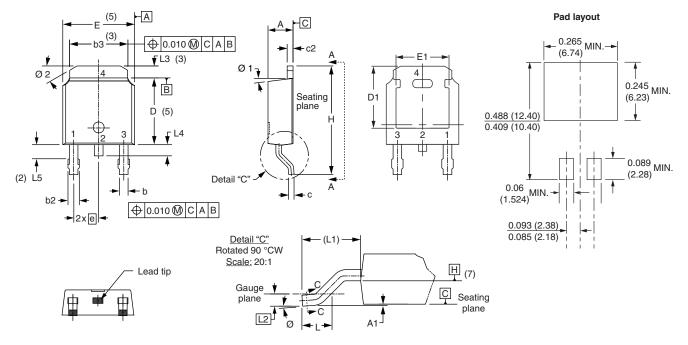
| LINKS TO RELATED DOCUMENTS | | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?95016 | | | | | | |
| Part marking information | www.vishay.com/doc?95059 | | | | | | |
| Packaging information | www.vishay.com/doc?95033 | | | | | | |





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIN | IETERS | INC | HES | NOTES | DTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|----------|--------|--------|-------|-------|-------|------|----------|-------------|-------|-----------|-------|-------|
| STIVIDOL | MIN. | MAX. | MIN. | MAX. | NOTES | | STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 2.18 | 2.39 | 0.086 | 0.094 | | | е | 2.29 | BSC | 0.090 | BSC | |
| A1 | - | 0.13 | - | 0.005 | | | Н | 9.40 | 10.41 | 0.370 | 0.410 | |
| b | 0.64 | 0.89 | 0.025 | 0.035 | | | L | 1.40 | 1.78 | 0.055 | 0.070 | |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 | | | L1 | 2.74 | BSC | 0.108 | REF. | |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 | 3 | | L2 | 0.51 BSC | | 0.020 BSC | | |
| С | 0.46 | 0.61 | 0.018 | 0.024 | | | L3 | 0.89 | 1.27 | 0.035 | 0.050 | 3 |
| c2 | 0.46 | 0.89 | 0.018 | 0.035 | | | L4 | - | 1.02 | - | 0.040 | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | 5 | | L5 | 1.14 | 1.52 | 0.045 | 0.060 | 2 |
| D1 | 5.21 | - | 0.205 | - | 3 | | Ø | 0° | 10° | 0° | 10° | |
| E | 6.35 | 6.73 | 0.250 | 0.265 | 5 | | Ø1 | 0° | 15° | 0° | 15° | |
| E1 | 4.32 | - | 0.170 | - | 3 | | Ø2 | 25° | 35° | 25° | 35° | |

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

(8) Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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